

Component	RM1	Rmtop	Cdecap	Rdecap	CGP	CGN	p-sub
Description	Metal 1 resistance	Metal top resistance	Power decoupling capacitance	Power decoupling resistance	Equivalent PMOS gate capacitance	Equivalent NMOS gate capacitance	Substrate resistivity
Dual-well	26Ω	5Ω	2.25 fF	2Ω	35.2 fF	25.2 fF	$0.01 \Omega \cdot \text{m}$
Triple-well	26Ω	5Ω	2.25 fF	2Ω	35.2 fF	25.2 fF	$0.01 \Omega \cdot \text{m}$
Component	RP	RN	CNW	RC-GND	RC-VDD	RNW	RPW
Description	PMOS equivalent resistance	NMOS equivalent resistance	Diode capacitance	GND to substrate access resistance	access resistance	N-well access resistance	access resistance
Dual-well	9.57Ω	5.3Ω	20 fF	$3.1 \text{ k}\Omega$	$3.1 \text{ k}\Omega$	n/a	n/a
Triple-well	9.57Ω	5.3Ω	20 fF	n/a	n/a	$3.1 \text{ k}\Omega$	$3.1 \text{ k}\Omega$